

MC74LCX244

Low-Voltage CMOS Octal Buffer

With 5 V-Tolerant Inputs and Outputs (3-State, Non-Inverting)

The MC74LCX244 is a high performance, non-inverting octal buffer operating from a 2.3 to 3.6 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A VI specification of 5.5 V allows MC74LCX244 inputs to be safely driven from 5 V devices. The MC74LCX244 is suitable for memory address driving and all TTL level bus oriented transceiver applications.

Current drive capability is 24 mA at the outputs. The Output Enable (\overline{OE}) input, when HIGH, disables the output by placing them in a HIGH Z condition.

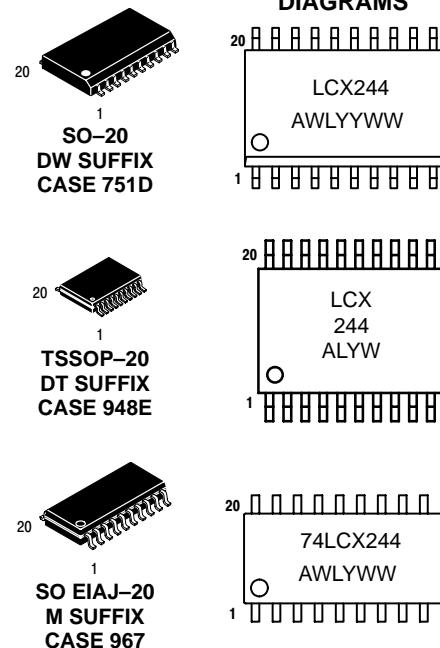
- Designed for 2.3 to 3.6 V V_{CC} Operation
- 5 V Tolerant – Interface Capability With 5 V TTL Logic
- Supports Live Insertion and Withdrawal
- I_{OFF} Specification Guarantees High Impedance When V_{CC} = 0 V
- LVTTL Compatible
- LVCMS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10 μ A) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500 mA
- ESD Performance: Human Body Model >2000 V; Machine Model >200 V



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MARKING DIAGRAMS



A = Assembly Location
L, WL = Wafer Lot
Y, YY = Year
W, WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
MC74LCX244DW	SO-20	38 Units/Rail
MC74LCX244DWR2	SO-20	1000 Units/Reel
MC74LCX244DT	TSSOP-20	75 Units/Rail
MC74LCX244DTEL	TSSOP-20	2000 Units/Reel
MC74LCX244DTR2	TSSOP-20	2500 Units/Reel
MC74LCX244M	SO EIAJ-20	40 Units/Rail
MC74LCX244MEL	SO EIAJ-20	2000 Units/Reel

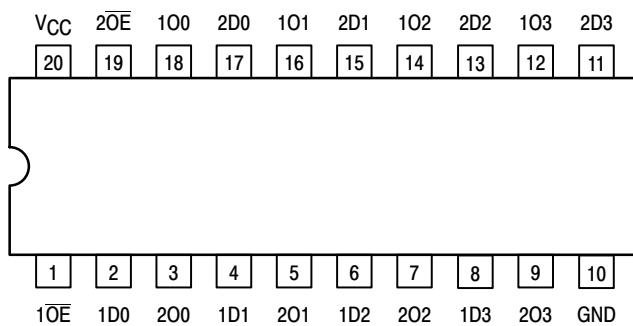
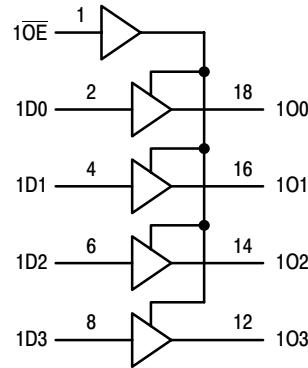


Figure 1. Pinout: 20-Lead (Top View)



PIN NAMES

PINS	FUNCTION
nOE	Output Enable Inputs
1Dn, 2Dn	Data Inputs
1On, 2On	3-State Outputs

TRUTH TABLE

INPUTS		OUTPUTS
1OE 2OE	1Dn 2Dn	1On, 2On
L	L	L
L	H	H
H	X	Z

H = High Voltage Level

L = Low Voltage Level

Z = High Impedance State

X = High or Low Voltage Level and Transitions are Acceptable

For I_{CC} reasons, DO NOT FLOAT Inputs

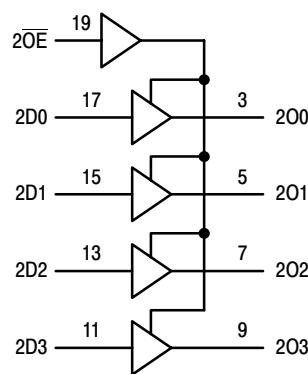


Figure 2. Logic Diagram

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MAXIMUM RATINGS

Symbol	Parameter	Value	Condition	Unit
V _{CC}	DC Supply Voltage	−0.5 to +7.0		V
V _I	DC Input Voltage	−0.5 ≤ V _I ≤ +7.0		V
V _O	DC Output Voltage	−0.5 ≤ V _O ≤ +7.0	Output in 3-State	V
		−0.5 ≤ V _O ≤ V _{CC} + 0.5	Output in HIGH or LOW State (Note 1.)	V
I _{IK}	DC Input Diode Current	−50	V _I < GND	mA
I _{OK}	DC Output Diode Current	−50	V _O < GND	mA
		+50	V _O > V _{CC}	mA
I _O	DC Output Source/Sink Current	±50		mA
I _{CC}	DC Supply Current Per Supply Pin	±100		mA
I _{GND}	DC Ground Current Per Ground Pin	±100		mA
T _{STG}	Storage Temperature Range	−65 to +150		°C

Maximum Ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute maximum-rated conditions is not implied. Functional operation should be restricted to the Recommended Operating Conditions.

1. I_O absolute maximum rating must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Typ	Max	Unit
V _{CC}	Supply Voltage Operating Data Retention Only	2.0 1.5	2.5, 3.3 2.5, 3.3	3.6 3.6	V
V _I	Input Voltage	0		5.5	V
V _O	Output Voltage (HIGH or LOW State) (3-State)	0 0		V _{CC} 5.5	V
I _{OH}	HIGH Level Output Current V _{CC} = 3.0 V – 3.6 V V _{CC} = 2.7 V – 3.0 V			−24 −12	mA
I _{OL}	LOW Level Output Current V _{CC} = 3.0 V – 3.6 V V _{CC} = 2.7 V – 3.0 V			24 12	mA
T _A	Operating Free-Air Temperature	−40		+85	°C
Δt/ΔV	Input Transition Rise or Fall Rate, V _{IN} from 0.8 V to 2.0 V, V _{CC} = 3.0 V	0		10	ns/V

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DC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic	Condition	$T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$		Unit
			Min	Max	
V_{IH}	HIGH Level Input Voltage (Note 2.)	$2.3 \leq V_{CC} \leq 2.7 \text{ V}$	1.7		V
		$2.7 \leq V_{CC} \leq 3.6 \text{ V}$	2.0		
V_{IL}	LOW Level Input Voltage (Note 2.)	$2.3 \leq V_{CC} \leq 2.7 \text{ V}$		0.7	V
		$2.7 \leq V_{CC} \leq 3.6 \text{ V}$		0.8	
V_{OH}	HIGH Level Output Voltage	$2.3 \leq V_{CC} \leq 3.6 \text{ V}; I_{OL} = 100 \mu\text{A}$	$V_{CC} - 0.2$		V
		$V_{CC} = 2.3 \text{ V}; I_{OH} = -8 \text{ mA}$	1.8		
		$V_{CC} = 2.7 \text{ V}; I_{OH} = -12 \text{ mA}$	2.2		
		$V_{CC} = 3.0 \text{ V}; I_{OH} = -18 \text{ mA}$	2.4		
		$V_{CC} = 3.0 \text{ V}; I_{OH} = -24 \text{ mA}$	2.2		
V_{OL}	LOW Level Output Voltage	$2.3 \leq V_{CC} \leq 3.6 \text{ V}; I_{OL} = 100 \mu\text{A}$		0.2	V
		$V_{CC} = 2.3 \text{ V}; I_{OL} = 8 \text{ mA}$		0.6	
		$V_{CC} = 2.7 \text{ V}; I_{OL} = 12 \text{ mA}$		0.4	
		$V_{CC} = 3.0 \text{ V}; I_{OL} = 16 \text{ mA}$		0.4	
		$V_{CC} = 3.0 \text{ V}; I_{OL} = 24 \text{ mA}$		0.55	
I_I	Input Leakage Current	$2.3 \leq V_{CC} \leq 3.6 \text{ V}; 0 \leq V_I \leq 5.5 \text{ V}$		± 5	μA
I_{OZ}	3-State Output Current	$2.3 \leq V_{CC} \leq 3.6 \text{ V}; 0 \leq V_O \leq 5.5 \text{ V}; V_I = V_{IH} \text{ or } V_{IL}$		± 5	μA
I_{OFF}	Power-Off Leakage Current	$V_{CC} = 0 \text{ V}; V_I \text{ or } V_O = 5.5 \text{ V}$		10	μA
I_{CC}	Quiescent Supply Current	$2.3 \leq V_{CC} \leq 3.6 \text{ V}; V_I = \text{GND or } V_{CC}$		10	μA
		$2.3 \leq V_{CC} \leq 3.6 \text{ V}; 3.6 \leq V_I \text{ or } V_O \leq 5.5 \text{ V}$		± 10	
ΔI_{CC}	Increase in I_{CC} per Input	$2.3 \leq V_{CC} \leq 3.6 \text{ V}; V_{IH} = V_{CC} - 0.6 \text{ V}$		500	μA

2. These values of V_I are used to test DC electrical characteristics only.

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AC CHARACTERISTICS ($t_R = t_F = 2.5$ ns; $R_L = 500 \Omega$)

Symbol	Parameter	Waveform	Limits						Unit	
			$T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$							
			$V_{CC} = 3.0$ V to 3.6 V		$V_{CC} = 2.7$ V		$V_{CC} = 2.5$ V ± 0.2			
			$C_L = 50$ pF		$C_L = 50$ pF		$C_L = 30$ pF			
			Min	Max	Min	Max	Min	Max		
t_{PLH}	Propagation Delay Input to Output	1	1.5	6.5	1.5	7.5	1.5	7.8	ns	
t_{PHL}			1.5	6.5	1.5	7.5	1.5	7.8		
t_{PZH}	Output Enable Time to High and Low Level	2	1.5	8.0	1.5	9.0	1.5	10	ns	
t_{PZL}			1.5	8.0	1.5	9.0	1.5	10		
t_{PHZ}	Output Disable Time From High and Low Level	2	1.5	7.0	1.5	8.0	1.5	8.4	ns	
t_{PLZ}			1.5	7.0	1.5	8.0	1.5	8.4		
t_{OSHL}	Output-to-Output Skew (Note 3.)			1.0					ns	
t_{OSLH}				1.0						

3. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

DYNAMIC SWITCHING CHARACTERISTICS

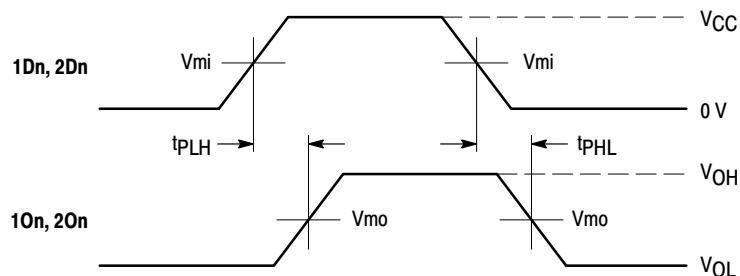
Symbol	Characteristic	Condition	$T_A = +25^\circ\text{C}$			Unit
			Min	Typ	Max	
V_{OLP}	Dynamic LOW Peak Voltage (Note 4.)	$V_{CC} = 3.3$ V, $C_L = 50$ pF, $V_{IH} = 3.3$ V, $V_{IL} = 0$ V $V_{CC} = 2.5$ V, $C_L = 30$ pF, $V_{IH} = 2.5$ V, $V_{IL} = 0$ V		0.8 0.6		V
V_{OLV}	Dynamic LOW Valley Voltage (Note 4.)	$V_{CC} = 3.3$ V, $C_L = 50$ pF, $V_{IH} = 3.3$ V, $V_{IL} = 0$ V $V_{CC} = 2.5$ V, $C_L = 30$ pF, $V_{IH} = 2.5$ V, $V_{IL} = 0$ V		-0.8 -0.6		V

4. Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

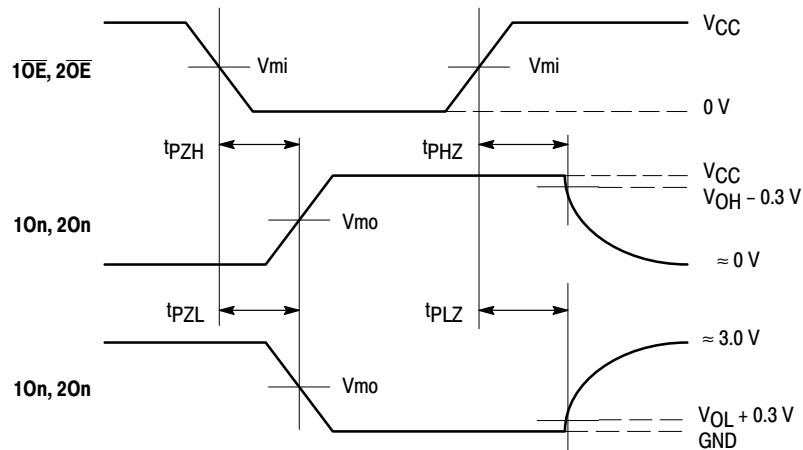
CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C_{IN}	Input Capacitance	$V_{CC} = 3.3$ V, $V_I = 0$ V or V_{CC}	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3$ V, $V_I = 0$ V or V_{CC}	8	pF
C_{PD}	Power Dissipation Capacitance	10 MHz, $V_{CC} = 3.3$ V, $V_I = 0$ V or V_{CC}	25	pF

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WAVEFORM 1 – PROPAGATION DELAYS
 $t_R = t_F = 2.5 \text{ ns}$, 10% to 90%; $f = 1 \text{ MHz}$; $t_W = 500 \text{ ns}$

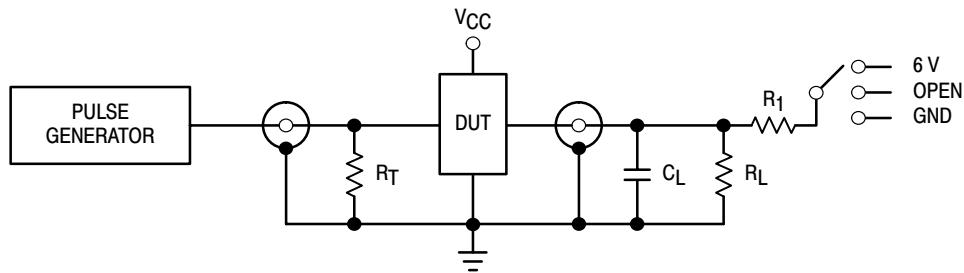


WAVEFORM 2 – OUTPUT ENABLE AND DISABLE TIMES
 $t_R = t_F = 2.5 \text{ ns}$, 10% to 90%; $f = 1 \text{ MHz}$; $t_W = 500 \text{ ns}$

Figure 3. AC Waveforms

Symbol	V_{CC}		
	3.3 V ± 0.3 V	2.7 V	2.5 V ± 0.2 V
V _{mi}	1.5 V	1.5 V	V _{CC} /2
V _{mo}	1.5 V	1.5 V	V _{CC} /2
V _{HZ}	V _{OL} + 0.3 V	V _{OL} + 0.3 V	V _{OL} + 0.15 V
V _{LZ}	V _{OH} - 0.3 V	V _{OH} - 0.3 V	V _{OH} - 0.15 V

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TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6 V at $V_{CC} = 3.3 \pm 0.3\text{ V}$ 6 V at $V_{CC} = 2.5 \pm 0.2\text{ V}$
Open Collector/Drain t_{PLH} and t_{PHL}	6 V
t_{PZH}, t_{PHZ}	GND

$C_L = 50\text{ pF}$ at $V_{CC} = 3.3 \pm 0.3\text{ V}$ or equivalent (includes jig and probe capacitance)

$C_L = 30\text{ pF}$ at $V_{CC} = 2.5 \pm 0.2\text{ V}$ or equivalent (includes jig and probe capacitance)

$R_L = R_1 = 500\text{ }\Omega$ or equivalent

$R_T = Z_{OUT}$ of pulse generator (typically $50\text{ }\Omega$)

Figure 4. Test Circuit